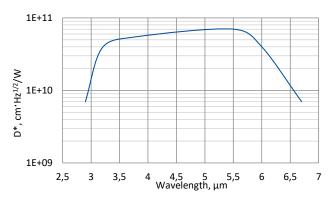


## 1.3 PVI-2TE-6-1×1-TO8-wZnSeAR-36

# 1.3.1 3.0 – 6.7 μm HgCdTe two stage thermoelectrically cooled, optically immersed photovoltaic detector

**PVI-2TE-6-1×1-TO8-wZnSeAR-36** is a two-stage thermoelectrically cooled IR photovoltaic detector based on sophisticated HgCdTe heterostructure for the best performance and stability. The device is optimized for maximum performance at 6 µm. The detector element is monolithically integrated with hyperhemispherical GaAs microlens to improve the performance of the device. Reverse bias may significantly increase response speed and dynamic range. 3° wedged zinc selenide anti-reflection coated (wZnSeAR) window prevents unwanted interference effects.

## Spectral response ( $T_a = 20$ °C, $V_b = 0$ mV)





Exemplary spectral detectivity, the spectral response of delivered devices may differ.

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## Specification ( $T_a = 20$ °C, $V_b = 0$ mV)

Parameter	Detector type
	PVI-2TE-6-1×1-TO8-wZnSeAR-36
Active element material	epitaxial HgCdTe heterostructure
Cut-on wavelength λ <sub>cut-on</sub> (10%), μm	2.4±0.5
Peak wavelength $\lambda_{\text{peak'}}$ $\mu\text{m}$	5.2±0.5
Optimum wavelength $\lambda_{ ext{opt'}}$ $\mu$ m	6.0
Cut-off wavelength $\lambda_{\text{cut-off}}$ (10%), $\mu$ m	6.7±0.3
Detectivity D*( $\lambda_{peak}$ ), cm·Hz <sup>1/2</sup> /W	≥7.0×10¹0
Detectivity D*(∆ <sub>opt</sub> ), cm·Hz¹/²/W	≥4.0×10 <sup>10</sup>
Current responsivity $R_i(\lambda_{peak})$ , A/W	≥2.7
Current responsivity $R_i(\lambda_{opt})$ , A/W	≥1.5
Time constant τ, ns	≤50
Resistance R, Ω	≥200
Active element temperature T <sub>det</sub> , K	~230
Optical area A <sub>o</sub> , mm×mm	1×1
Package	TO8
Acceptance angle Φ	~36°
Window	wZnSeAR

#### **Features**

- High performance
- Wide dynamic range
- Versatility
- Quantity discounted price
- Fast delivery

# **Applications**

- Gas detection, monitoring, and analysis (CO, CO<sub>2</sub>, NH<sub>3</sub>, NO<sub>x</sub>)
- Flue gas denitrification
- Fuel combustion monitoring at power plants and other industrial facilities
- Contactless temperature measurements

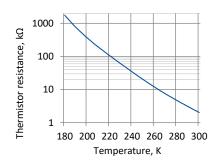
#### **Related product**

• UM-I-6 detection module

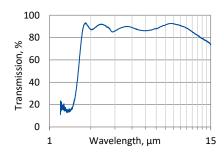
#### Two-stage thermoelectric cooler parameters

Parameter	Value
T <sub>det</sub> , K	~230
V <sub>max</sub> , V	1.3
I <sub>max</sub> , A	1.2
Q <sub>max</sub> , W	0.36

#### **Thermistor characteristics**



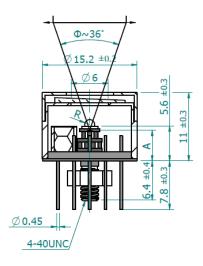
#### Spectral transmission of wZnSeAR window (typical example)



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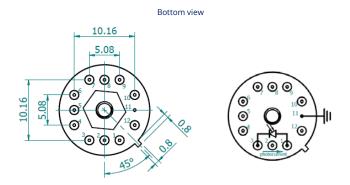


#### Mechanical layout, mm



Parameter	Value
Immersion microlens shape	hyperhemisphere
Optical area A <sub>o</sub> , mm×mm	1×1
R, mm	0.8
A, mm	3.2±0.3

 $\Phi$  – acceptance angle, R – hyperhemisphere microlens radius, A – distance from the bottom of the 2TE-TO8 header to the focal plane



Function	Pin number
Detector	1, 3
Reverse bias (optional)	1(-), 3(+)
Thermistor	7, 9
TE cooler supply	2(+), 8(-)
Chassis ground	11
Not used	4, 5, 6, 10, 12

#### Precautions for use and storage

- Standard ohmmeter may overbias and damage the detector. The bias of 10 mV can be used for resistance measurements.
- Heatsink with a thermal resistance of  $\sim$ 2 K/W is necessary to dissipate heat generated by 2TE cooler.
- Operation in 10% to 80% humidity and -20°C to 30°C ambient temperature.
- Beam power limitations for optically immersed detector:
  - irradiance with CW or single pulse longer than 1 µs irradiance on the apparent optical active area must not exceed 2.5 W/cm²,
  - irradiance of the pulse shorter than 1 µs must not exceed 10 kW/cm<sup>2</sup>.
- Storage in a dark place with 10% to 90% humidity and -20°C to 50°C ambient temperature.

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